

Composite Transistors

XP01112 (XP1112)

Silicon PNP epitaxial planer transistor

For switching/digital circuits

■ Features

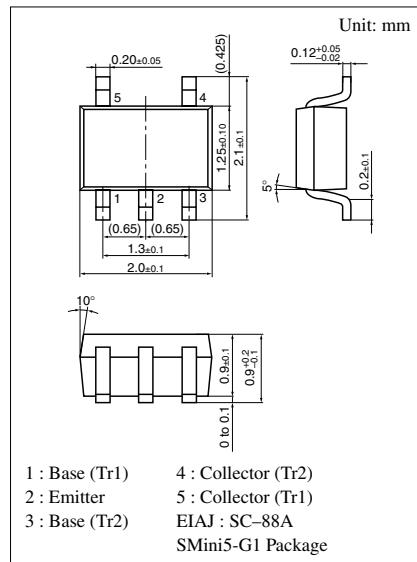
- Two elements incorporated into one package.
(Emitter-coupled transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half.

■ Basic Part Number of Element

- UNR1112(UN1112) \times 2 elements

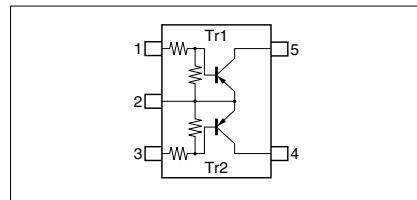
Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Ratings	Unit
Rating of element	Collector to base voltage	V_{CBO}	-50	V
	Collector to emitter voltage	V_{CEO}	-50	V
	Collector current	I_C	-100	mA
Overall	Total power dissipation	P_T	150	mW
	Junction temperature	T_j	150	°C
	Storage temperature	T_{stg}	-55 to +150	°C



Marking Symbol: 7K

Internal Connection

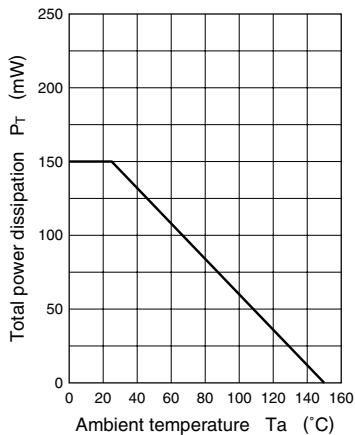
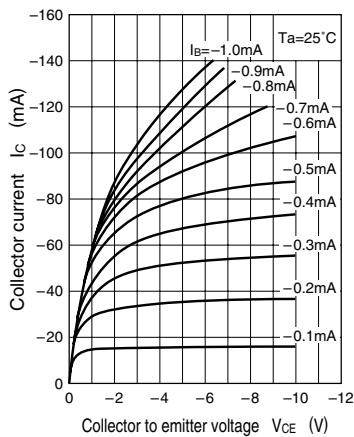
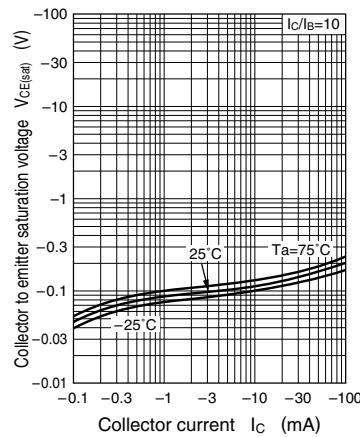
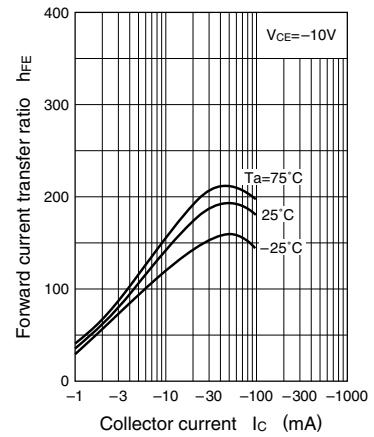
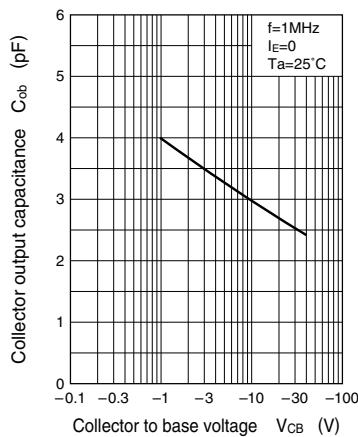
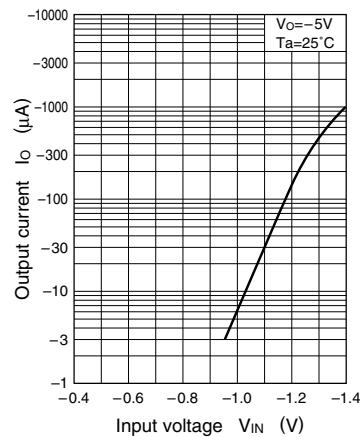
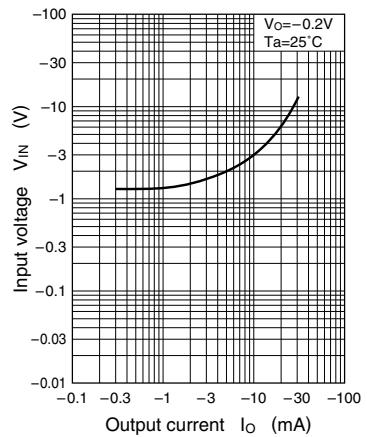


■ Electrical Characteristics (Ta=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector to base voltage	V_{CBO}	$I_C = -10\mu A, I_E = 0$	-50			V
Collector to emitter voltage	V_{CEO}	$I_C = -2mA, I_B = 0$	-50			V
Collector cutoff current	I_{CBO}	$V_{CB} = -50V, I_E = 0$			-0.1	μA
	I_{CEO}	$V_{CE} = -50V, I_B = 0$			-0.5	μA
Emitter cutoff current	I_{EBO}	$V_{EB} = -6V, I_C = 0$			-0.2	mA
Forward current transfer ratio	h_{FE}	$V_{CE} = -10V, I_C = -5mA$	60			
Forward current transfer h_{FE} ratio	h_{FE} (small/large) [†]	$V_{CE} = -10V, I_C = -5mA$	0.5	0.99		
Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_C = -10mA, I_B = -0.3mA$			-0.25	V
Output voltage high level	V_{OH}	$V_{CC} = -5V, V_B = -0.5V, R_L = 1k\Omega$	-4.9			V
Output voltage low level	V_{OL}	$V_{CC} = -5V, V_B = -2.5V, R_L = 1k\Omega$			-0.2	V
Transition frequency	f_T	$V_{CB} = -10V, I_E = 1mA, f = 200MHz$		80		MHz
Input resistance	R_I		-30%	22	+30%	$k\Omega$
Resistance ratio	R_I/R_2		0.8	1.0	1.2	

*¹ Ratio between 2 elements

Note) The Part number in the Parenthesis shows conventional part number.

P_T — Ta I_C — V_{CE}  $V_{CE(sat)}$ — I_C  h_{FE} — I_C  C_{ob} — V_{CB}  I_O — V_{IN}  V_{IN} — I_O 

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